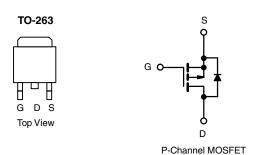


www.vishay.com

Vishay Siliconix

Automotive P-Channel 40 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	- 40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0094				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0170				
I _D (A)	- 50				
Configuration	Single				



FEATURES

- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- 100 % R_q and UIS Tested
- AEC-Q101 Qualified^d
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912



ROHS COMPLIANT HALOGEN FREE

ORDERING INFORMATION	
Package	TO-263
Lead (Pb)-free and Halogen-free	SQM50P04-09L-GE3

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-Source Voltage	V_{DS}	- 40	V			
Gate-Source Voltage	V_{GS}	± 20	V			
Continuous Drain Currenta	T _C = 25 °C	ı	- 50			
Continuous Drain Current	T _C = 125 °C	Ι _D	- 50			
Continuous Source Current (Diode Conduc	I _S	- 50	Α			
Pulsed Drain Current ^b	I _{DM}	- 200				
Single Pulse Avalanche Current	. 0.111	I _{AS}	- 50			
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	125	mJ		
Mariana Barras Biaria atianh	T _C = 25 °C	Б	150	14/		
Maximum Power Dissipation ^b	T _C = 125 °C	P_{D}	50	W		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	°C		

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	40	°C/W		
Junction-to-Case (Drain)		R _{thJC}	1	3C/W		

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



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SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static					•			
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		- 40	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		- 2.0	- 2.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = - 40 V	1	-	- 1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	- 50	μΑ	
		$V_{GS} = 0 V$	V _{DS} = - 40 V, T _J = 175 °C	-	-	- 250	1	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 10 V	$V_{DS} \le -5 V$	- 100	-	-	Α	
		V _{GS} = - 10 V	I _D = - 50 A	-	0.0078	0.0094	Ω	
Drain Course On State Desistance	D	V _{GS} = - 10 V	I _D = - 50 A, T _J = 125 °C	-	-	0.0139		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V	I _D = - 50 A, T _J = 175 °C	=.	-	0.0162		
		V _{GS} = - 4.5 V	= - 4.5 V I _D = - 25 A		0.0138	0.0170		
Forward Transconductanceb	9 _{fs}	V _{DS} = - 15 V, I _D = - 50 A		-	70	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}		V _{GS} = 0 V V _{DS} = - 10 V, f = 1 MHz		4836	6045	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$			1129	1415		
Reverse Transfer Capacitance	C _{rss}			-	959	1200	1	
Total Gate Charge ^c	Qg			1	96.5	145		
Gate-Source Charge ^c	Q_{gs}	V _{GS} = - 10 V	$V_{DS} = -20 \text{ V}, I_{D} = -50 \text{ A}$	1	21.4	-	nC	
Gate-Drain Charge ^c	Q_{gd}]		-	16.6	-		
Gate Resistance	R_g	f = 1 MHz		1.2	2.56	3.9	Ω	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 20 \text{ V}, \text{ R}_{L} = 0.4 \Omega$ $I_{D} \cong 50 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$		-	12	18		
Rise Time ^c	t _r			-	13	20	- ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	61	91		
Fall Time ^c	t _f			=	18	27		
Source-Drain Diode Ratings and Characteristics ^b								
Pulsed Current ^a	I _{SM}			-	-	- 200	Α	
Forward Voltage	V _{SD}	I _F = - 40 A, V _{GS} = 0 V		-	- 0.95	- 1.5	V	

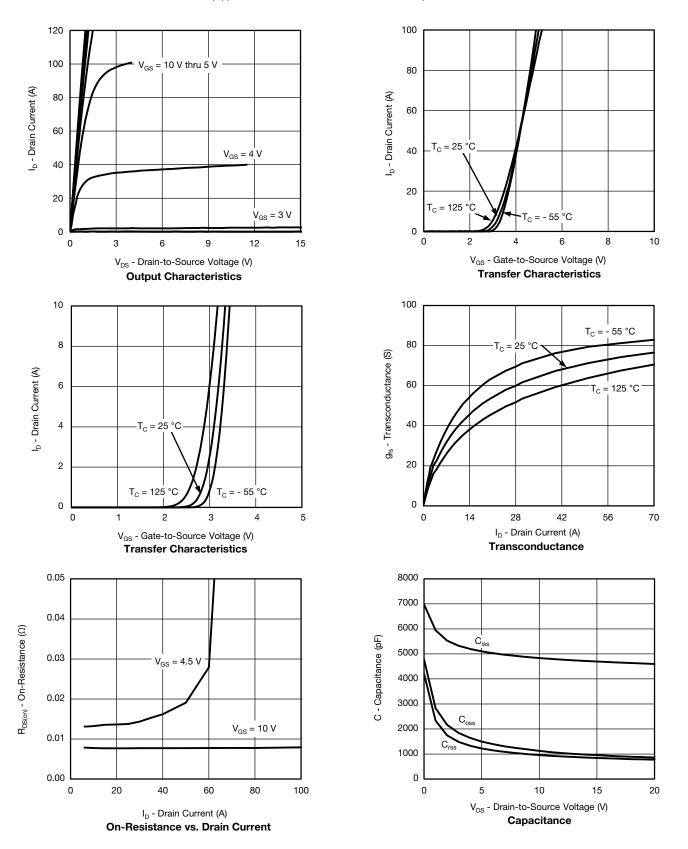
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

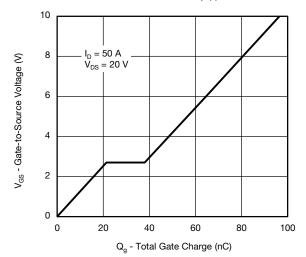


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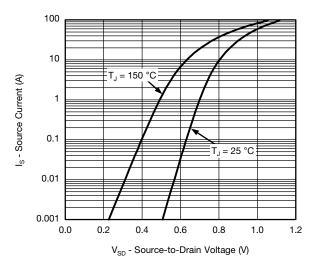


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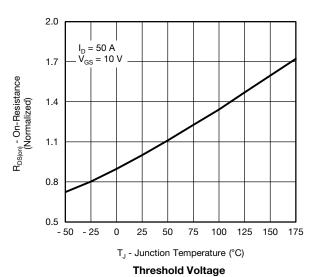
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

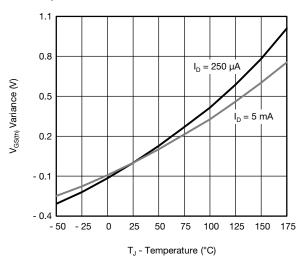




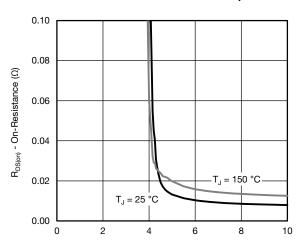


Source Drain Diode Forward Voltage

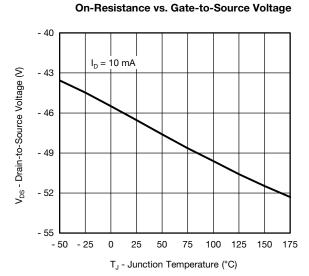




On-Resistance vs. Junction Temperature



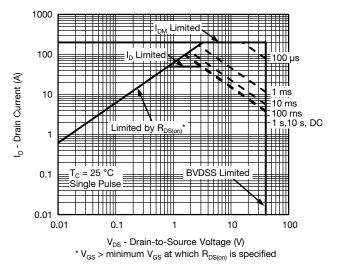
V_{GS} - Gate-to-Source Voltage (V)



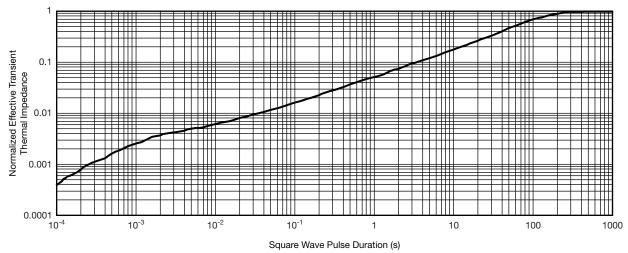
Drain Source Breakdown vs. Junction Temperature

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



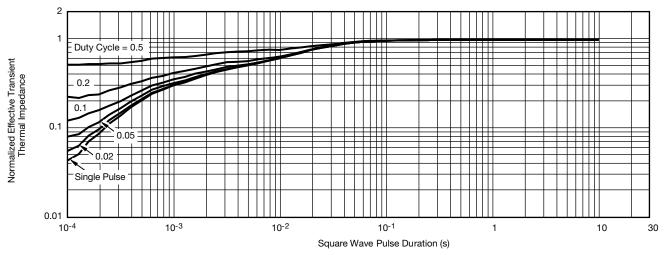
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part

pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg267032.



TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



_ - b1 , , ,	
≥ 	- -

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6. This feature is for thick lead.

		INCHES		MILLIMETERS		
DIM.		MIN.	MIN. MAX.		MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
-*	Thin lead	0.013	0.018	0.330	0.457	
C*	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
D		0.340	0.380	8.636	9.652	
D1		0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
D4		0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	=	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100) BSC	2.54 BSC		
	K	0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4	0.010) BSC	0.254	BSC	
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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